IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re: Young-pil Kim et al. Serial No.: To Be Assigned Filed: Concurrently Herewith

For: Semiconductor Device Test Patterns and Related Methods for Precisely

Measuring Leakage Currents in Semiconductor Cell Transistors

Date: March 9, 2004

Mail Stop Patent Application Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. § 1.97(b)

Sir:

Attached is a list of documents on Form PTO-1449, together with a copy of any listed foreign patent document and/or non-patent literature. A copy of any listed U.S. patent and/or U.S. patent application publication is not provided herewith in accordance with the waiver by the U.S. Patent and Trademark Office of requirements under 37 C.F.R. § 1.98(a)(2)(i) for all U.S. national patent applications filed after June 30, 2003 and for all international applications that have entered the national stage under 35 USC § 371 after June 30, 2003.

It is requested that these documents be considered by the Examiner and officially made of record in accordance with the provisions of 37 C.F.R. § 1.56 and Section 609 of the MPEP.

No fee is believed due. However, the Commissioner is hereby authorized to charge any deficiency or credit any overpayment to Deposit Account No. 50-0220.

Respectfully submitted,

D. Randal Ayers

Registration No. 40,493

Myers Bigel Sibley & Sajovec, P.A.

P. O. Box 37428

Raleigh, North Carolina 27627 Telephone: (919) 854-1400 Facsimile: (919) 854-1401

Customer No. 20792

CERTIFICATE OF EXPRESS MAILING

Express Mail Label No. EV 381443985US

Date of Deposit: March 9, 2004

I hereby certify that this correspondence is being deposited with the United States Postal Service "Express Mail Post Office to Addressee" service under 37 CFR § 1.10 on the date indicated above and is addressed to: Mail Stop PATENT APPLICATION, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Michele P. McMahan

Substitute form 1449A/PTO					Complete if Known		
				Application Number	To Be Assigned		
INFORMATION DISCLOSURE				Filing Date	Concurrently Herewith		
STATEMENT BY APPLICANT (use as many sheets as necessary)			•	First Named Inventor	Young-pil Kim et al.		
			•	Group Art Unit	Unknown		
			•	Examiner Name	Unknown		
Sheet	1	of	1	Attorney Docket Number	5649-1276		

U.S. PATENTS AND PATENT PUBLICATIONS						
Examiner Initials*	Cite No.	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document	
		Number	Kind Code (if known)	- Document	MM-DD-YYYY	
					11/22/2001	
		- · · · · · · · · · · · · · · · · · · ·				
				40-40-40		
					44°44.44°48°48°40°400°400°	
-						
	ļ					

FOREIGN PATENT DOCUMENTS								
Examiner Initials*	Cite	Foreign Patent Document			Name of Patentee or Applicant of Cited	Date of Publication	Т	T
	No.	Office	Number	Kind Code (if known)	Document	of Cited Document MM-DD-YYYY		
	ļ							
	ļ	ļ						
						ļ <u>.</u>		
		1	· · · · · · · · · · · · · · · · · · ·		1 - 141		L,	
	1						\sqcup	
	<u> </u>	<u> </u>						L

Examiner Initials*	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T
	1	Young Pil Kim et al., "Reliability Degradation of High Density DRAM Cell Transistor Junction Leakage Current Induced by Band-to-Defect tunneling Under the Off-State Bias-Temperature Stress," <u>IEEE</u> , 2001	
	2	K. Saino et al., "Impact of Gate-Induced Drain Leakage Current on the Tail Distribution of DRAM Data Retention Time," IEEE, 2000	

Examiner Signature	Date Considered	